NSN 5961-01-019-4953

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Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Field effect-dual gate
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-18
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current of standard range
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector preset
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0